

Technical Data Data Sheet N1365, Rev. - **Green Products**

STF15120C(R) SCHOTTKY RECTIFIER

Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features:

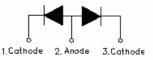
- 150 °C T J operation
- Center tap configuration
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device

Mechanical Dimensions: In mm

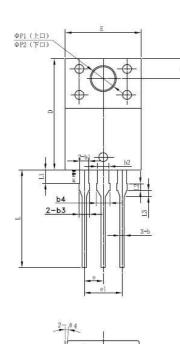
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



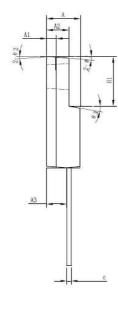
STF15120C



STF15120CR



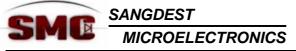
ահ աթ ար



SYMBOL	MIN.	TYP.	MAX.
A	4.30	4.50	4.70
A1	1.10	1.30	1.50
A2	2.80	3.00	3.20
A3	2.50	2.70	2.90
A3 b	0.50	0.60	0.75
b1	1.10	1.20	1.35
b2	1.50	1.60	1.75
b3	1.20	1.30	1.45
b4	1.60	1.70	1.85
b4 c D E	0.55	0.60	0.75
D	14.80	15.00	15.20
E	9.96	10.16	10.36
е		2.55	
e1		5.10	
H1	6.50	6.70	6.90
L	12.70	13.20	13.70
L1	1.60	1.80	2.00
L2	0.80	1.00	1.20
L3	0.60	0.80	1.00
ΦΡ1(上口)	3.30	3.50	3.70
ΦΡ2(下口)	2.99	3.19	3.39
Q	2.50	2.70	2.90
Θ1		5°	
Θ2		4°	
Θ3		10°	
Θ4		5°	
Θ5		5°	

ITO-220AB

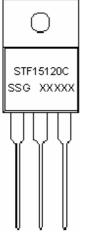
Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 (86) 25-87123907 •
FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •

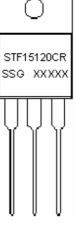


Technical Data Data Sheet N1365, Rev. -

Green Products

Marking Diagram:





STF15120C

Cautions: Molding resin

STF15120CR

Where XXXXX is YYWWL

S T F 15 120 C(R) SSG YY WW	 Device Type Ultralow VF Package type Forward Current (15A) Reverse Voltage (120V) Configuration SSG Year Week
VV VV	
L	= Lot Number

Epoxy resin UL: 94V-0

Ordering Information:

Device	Package	Shipping
STF15120C(R)	ITO-220AB (Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V _{RWM}	-	120	V
Average Forward Current	I _{F(AV)}	50% duty cycle @T _C =105 °C rectangular wave form	15	А
Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	130	А

Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 (86) 25-87123907 •
 FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •



Technical Data Data Sheet N1365, Rev. - **Green Products**

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop (per	V _{F1}	@ 7.5A, Pulse, T _J = 25 °C	0.88	V
leg)*	V _{F2}	@ 7.5A, Pulse, T _J = 125 °C	0.71	V
Reverse Current (per leg)	I _{R1}	@V _R = rated V _R T _J = 25 °C	0.6	mA
Reverse Current (per leg) *	I _{R2}	$@V_R = rated V_R$ T _J = 125 °C	40	mA
Junction Capacitance (per leg)	C _T	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	450	pF
Voltage Rate of Change	dv/dt	-	10,000	V/µs
RSM Isolation Voltage (t = 1.0 second, R. H. < =30%, $T_A = 25 \text{ °C}$)		Clip mounting, the epoxy body away from the heatsink edge by more than 0.110" along the lead direction.	4500	
	V _{ISO}	Clip mounting, the epoxy body is inside the heatsink.	3500	V
		Screw mounting, the epoxy body is inside the heatsink.	1500	

* Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case (per leg)	R _{θJC}	DC operation	5.5	°C/W
Approximate Weight	wt	-	2	g
Case Style		ITO-220AB		



Technical Data Data Sheet N1365, Rev. -

Green Products

DISCLAIMER:

1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC - Sangdest Microelectronics (Nanjing) Co., Ltd sales department for the latest version of the datasheet(s).

2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment , and safety equipment) , safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement .

3- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC - Sangdest Microelectronics (Nanjing) Co., Ltd assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.

4- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.

5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations.